

RELIABILITY REPORT FOR MAX6699UE34+ PLASTIC ENCAPSULATED DEVICES

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MAXIM INTEGRATED PRODUCTS

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Conclusion

The MAX6699UE34+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX6699 precision multichannel temperature sensor monitors its own temperature and the temperatures of up to four external diode-connected transistors. All temperature channels have programmable alert thresholds. Channels 1 and 4 also have programmable overtemperature thresholds. When the measured temperature of a channel exceeds the respective threshold, a status bit is set in one of the status registers. Two open-drain outputs, active-low OVERT and active-low ALERT, assert corresponding to these bits in the status register. The 2-wire serial interface supports the standard system management bus (SMBus(tm)) protocols: write byte, read byte, send byte, and receive byte for reading the temperature data and programming the alarm thresholds. The MAX6699 is specified for an operating temperature range of -40°C to +125°C and is available in 16-pin QSOP and 16-pin TSSOP packages.



II. Manufacturing Information

MAX6699

A. Description/Function:	5-Channel Precision Temperature Monitor
B. Process:	B8
C. Number of Device Transistors:	21278
D. Fabrication Location:	California or Texas
E. Assembly Location:	Malaysia, Philippines, Thailand
F. Date of Initial Production:	October 22, 2005

III. Packaging Information

A. Package Type:	16-pin TSSOP
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-1209
H. Flammability Rating:	Class UL94-V0
 Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C 	Level 1
J. Single Layer Theta Ja:	106°C/W
K. Single Layer Theta Jc:	27°C/W
L. Multi Layer Theta Ja:	90°C/W
M. Multi Layer Theta Jc:	27°C/W

IV. Die Information

A. Dimensions:	77 X 107 mils
B. Passivation:	Si ₃ N ₄ /SiO ₂ (Silicon nitride/ Silicon dioxide)
C. Interconnect:	AI/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	0.8 microns (as drawn)
F. Minimum Metal Spacing:	0.8 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw



A. Quality Assurance Contacts:	Don Lipps (Manager, Reliability Engineering) Bryan Preeshl (Managing Director of QA)
B. Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet.0.1% For all Visual Defects.
C. Observed Outgoing Defect Rate:	< 50 ppm
D. Sampling Plan:	Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{\frac{1.83}{192 \text{ x } 4340 \text{ x } 48 \text{ x } 2}}_{(\text{where } 4340 \text{ = Temperature Acceleration factor assuming an activation energy of 0.8eV})$ $\lambda = 22.9 \text{ x } 10^{-9}$ $\lambda = 22.9 \text{ F.I.T. (60\% confidence level @ 25°C)}$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the B8 Process results in a FIT Rate of 0.06 @ 25C and 0.99 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The TS63 die type has been found to have all pins able to withstand a HBM transient pulse of +/-1500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA.



Table 1 Reliability Evaluation Test Results

MAX6699UE34+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test	(Note 1)				
	Ta = 135°C	DC Parameters	48	0	
	Biased	& functionality			
	Time = 192 hrs.				
Moisture Testing	(Note 2)				
HAST	Ta = 130°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 96hrs.				
Mechanical Stres	ss (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
	Method 1010	-			

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data